

INCHANGE SEMICONDUCTOR

isc Silicon NPN Darlington Power Transistor

2SD1414

DESCRIPTION

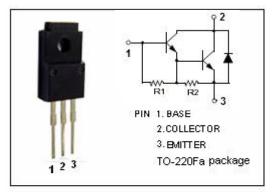
- Collector-Emitter Breakdown Voltage-: V_{(BR)CEO}= 80V(Min)
- Collector-Emitter Saturation Voltage-: V_{CE(sat)}= 1.5V(Max) @I_C= 3A
- High DC Current Gain
- : h_{FE}= 2000(Min) @ I_C= 1A, V_{CE}= 2V
- Complement to Type 2SB1024
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

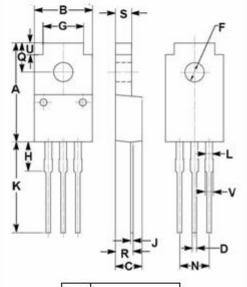
APPLICATIONS

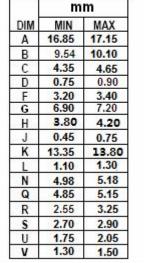
- Switching applications
- · Hammer driver, pulse motor driver applications
- · Power amplifier applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{CBO}	Collector-Base Voltage	100	V
V _{CEO}	Collector-Emitter Voltage	80	V
V _{EBO}	Emitter-Base Voltage	5	V
lc	Collector Current-Continuous	4	A
IB	Base Current-Continuous	0.5	A
Pc	Collector Power Dissipation @ $T_c=25^{\circ}C$	20	W
TJ	Junction Temperature	150	°C
T _{stg}	Storage Temperature Range	-55~150	°C







isc website: <u>www.iscsemi.com</u>



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ELECTRICAL CHARACTERISTICS

$T_{\text{C}}\text{=}25\,^{\circ}\!\!\!\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 10mA; I _B = 0	80			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 3A; I _B = 6mA			1.5	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 3Α; I _B = 6mΑ			2.0	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 100V; I _E = 0			20	μA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			2.5	mA
h _{FE -1}	DC Current Gain	I _C = 1A; V _{CE} = 2V	2000			
h _{FE -2}	DC Current Gain	I _C = 3A; V _{CE} = 2V	1000			

Switching times

t _{on}	Turn-on Time	I _{B1} = I _{B2} = 6mA R _L = 10 Ω ; V _{CC} = 30V P _W =20 μ s; Duty Cycle≤1%	0.2	μ S
t _{stg}	Storage Time		1.5	μ S
tŗ	Fall Time		0.6	μ s

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